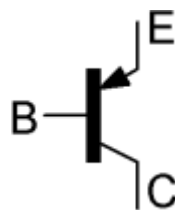


Silicon PNP Transistor

BSYP06

DATASHEET

60V / 600mA



OEM – Volksrepublik Polen

Source: Importbauelemente Transistoren Mikroelektronik Heft 8 HFO 1982

Technische Daten

| |
|-------------------------------|
| BSYP06 Silizium PNP |
|-------------------------------|

| Absolute Grenzwerte | | | |
|---------------------|------|----|------------|
| | UCB0 | V | 60 |
| | UCE0 | V | 40 |
| | UEB0 | V | 5 |
| | IC | mA | 600 |
| | Ptot | mW | 400 |
| | TJ | °C | - |

| Kennwerte bei Ta=25° | | | |
|-------------------------|-----|-----|----------------|
| h21E | bei | - | 40..120 |
| UCE0 | | V | 10 |
| IC | | mA | 150 |
| UCESAT | bei | V | <1,6 |
| IC/IB | | mA | 500/50 |
| fT | | Mhz | 200 |
| ton<=45nS; toff <=175nS | | | |

